



PJN1NA60A / PJW1NA60A / PJu1NA60A / PJD1NA60A

600V N-Channel MOSFET

Voltage **600 V**

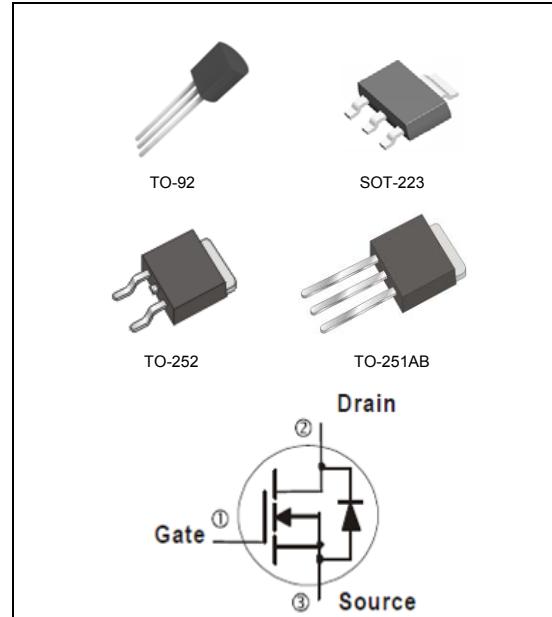
Current **1 A**

Features

- $R_{DS(ON)}$, $V_{GS} @ 10V, I_D @ 0.5A < 7.9\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case : TO-251AB, TO-252, SOT-223, TO-92 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AB Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252 Approx. Weight : 0.0104 ounces, 0.297grams
- SOT-223 Approx. Weight : 0.043 ounces, 0.123grams
- TO-92 Approx. Weight : 0.007 ounces, 0.196grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | TO-251AB/TO-252 | SOT-223 | TO-92 | UNITS | |
|---|---------------------------|-----------------|--------------------------|-------|--------------|---------------|
| Drain-Source Voltage | V_{DS} | 600 | | | V | |
| Gate-Source Voltage | V_{GS} | +30 | | | V | |
| Continuous Drain Current | I_D | 1 | 0.4 | | A | |
| Pulsed Drain Current | I_{DM} | 4 | 1.6 | | A | |
| Single Pulse Avalanche Energy ^(Note 1) | E_{AS} | 52 | | | mJ | |
| Power Dissipation | $T_C=25^\circ C$ | P_D | 28 | 3.3 | 3 | W |
| | Derate above $25^\circ C$ | | 0.22 | 0.026 | 0.024 | W/ $^\circ C$ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | | -55~150 | | $^\circ C$ | |
| Typical Thermal resistance | | | | | | |
| - Junction to Case | $R_{\theta JC}$ | 4.46 | - | - | $^\circ C/W$ | |
| - Junction to Ambient | $R_{\theta JA}$ | 110 | 37.9 ^(Note 4) | 140 | | |

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|--------------|--|------|----------|-----------|----------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 600 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 2 | 3.3 | 4 | V |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=0.5A$ | - | 7.2 | 7.9 | Ω |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=600V, V_{GS}=0V$ | - | 0.02 | 1.0 | μA |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS}=\pm 30V, V_{DS}=0V$ | - | ± 10 | ± 100 | nA |
| Diode Forward Voltage | V_{SD} | $I_S=1A, V_{GS}=0V$ | - | 0.88 | 1.4 | V |
| Dynamic <small>(Note 5)</small> | | | | | | |
| Total Gate Charge | Q_g | $V_{DS}=480V, I_D=1A,$ $V_{GS}=10V$ <small>(Note 2,3)</small> | - | 3.1 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 1.3 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 0.4 | - | |
| Input Capacitance | C_{iss} | $V_{DS}=25V, V_{GS}=0V,$ $f=1.0MHz$ | - | 148 | - | pF |
| Output Capacitance | C_{oss} | | - | 28 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 0.3 | - | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}=300V, I_D=1A,$ $R_G=25\Omega$ <small>(Note 2,3)</small> | - | 6 | - | ns |
| Turn-On Rise Time | t_r | | - | 20 | - | |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 9 | - | |
| Turn-Off Fall Time | t_f | | - | 26 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I_S | --- | - | - | 1 | A |
| Maximum Pulsed Drain-Source Diode Forward Current | I_{SM} | --- | - | - | 4 | A |
| Reverse Recovery Time | trr | $V_{GS}=0V, I_S=1A$ | - | 190 | - | ns |
| Reverse Recovery Charge | Qrr | $dI_F/dt=100A/\mu s$ <small>(Note 2)</small> | - | 0.53 | - | μC |

NOTES :

1. $L=30mH, I_{AS}=1.8A, V_{DD}=50V, R_G=25 \text{ ohm}$, Starting $T_J=25^\circ C$
2. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
3. Essentially independent of operating temperature typical characteristics
4. R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
5. Guaranteed by design, not subject to production testing



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TYPICAL CHARACTERISTIC CURVES

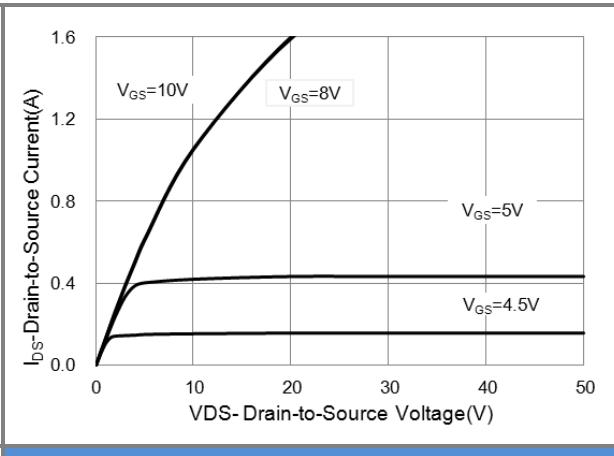


Fig.1 Output Characteristics

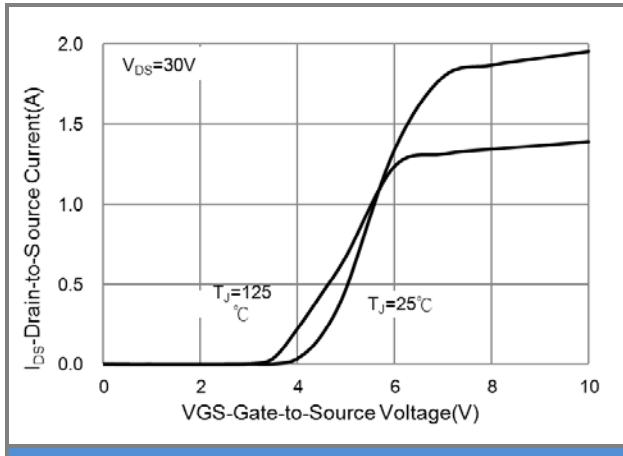


Fig.2 Transfer Characteristics

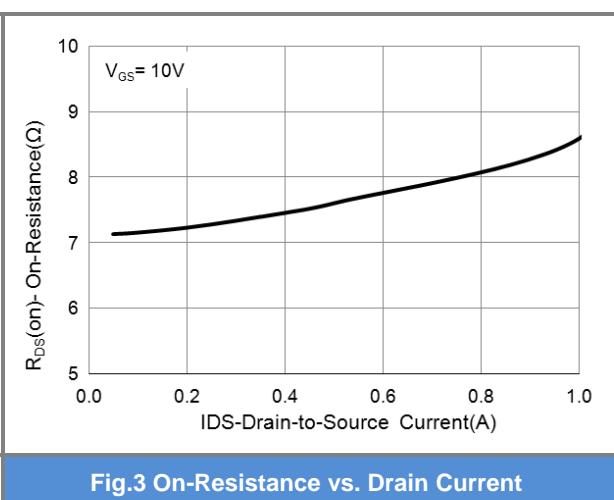


Fig.3 On-Resistance vs. Drain Current

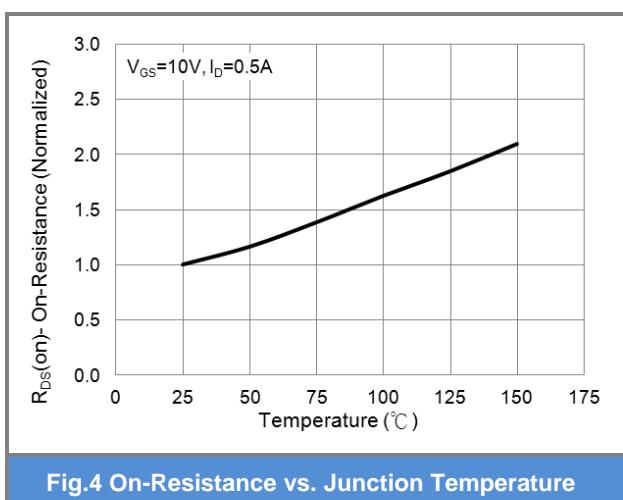


Fig.4 On-Resistance vs. Junction Temperature

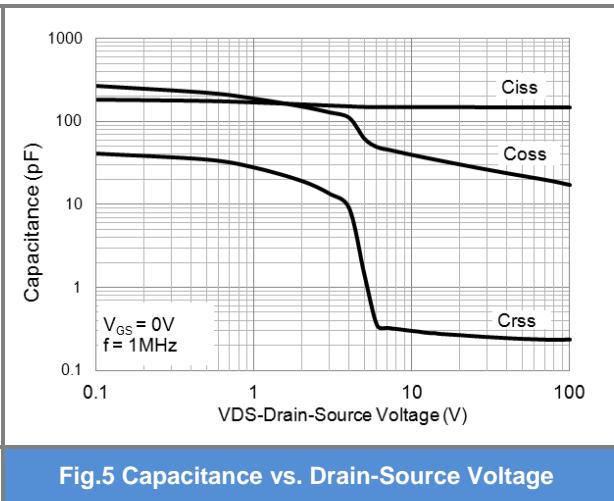


Fig.5 Capacitance vs. Drain-Source Voltage

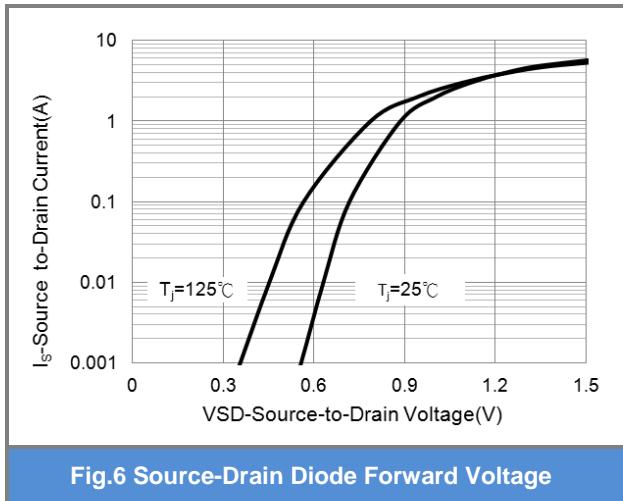


Fig.6 Source-Drain Diode Forward Voltage



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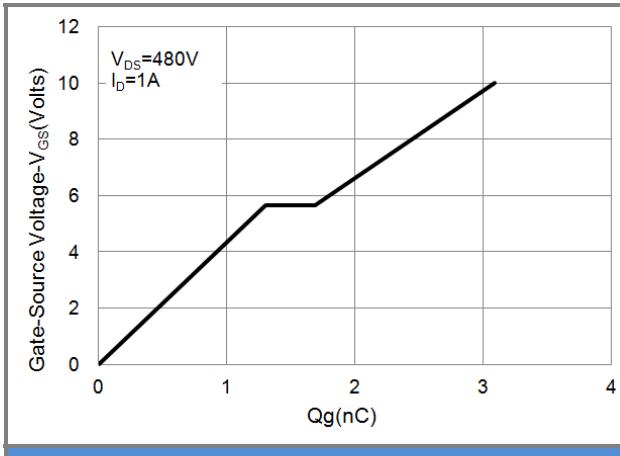


Fig.7 Gate Charge

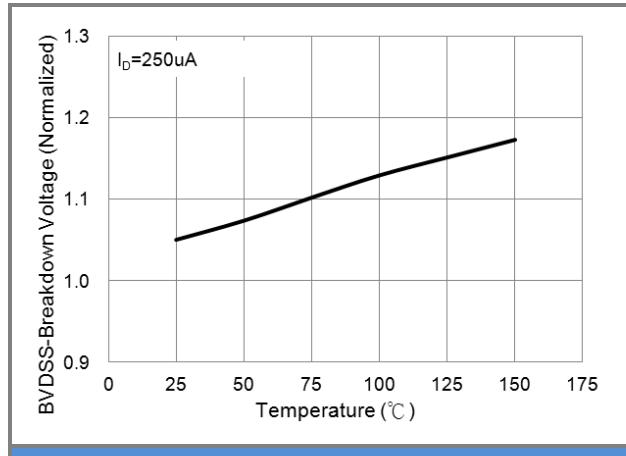


Fig.8 BV_{DSS} vs. Junction Temperature

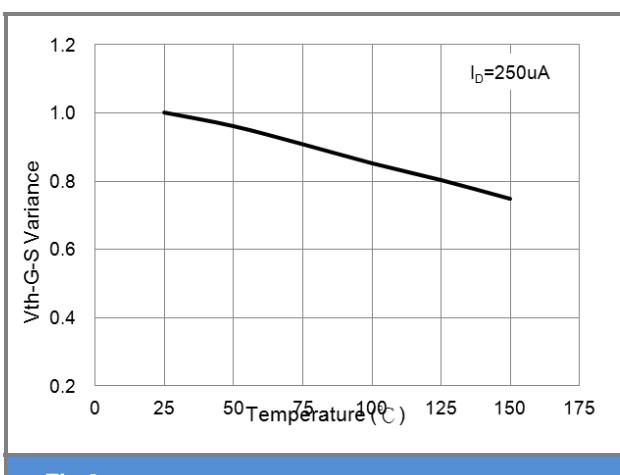


Fig.9 Threshold Voltage Variation with Temperature

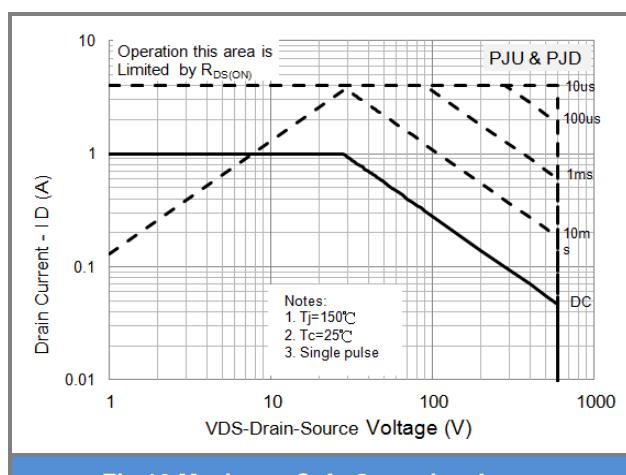


Fig.10 Maximum Safe Operating Area

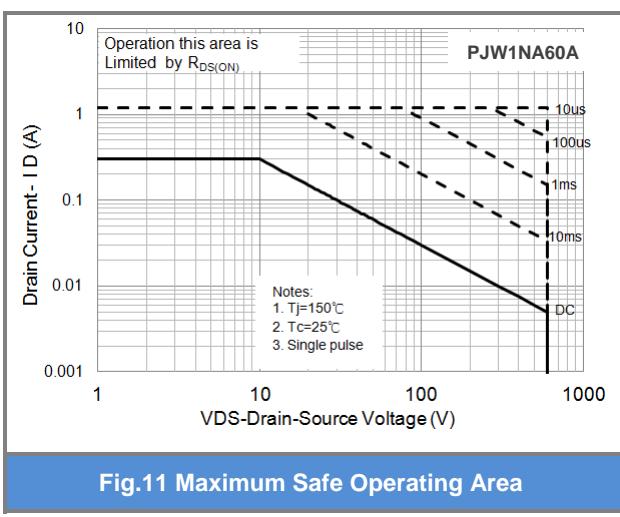


Fig.11 Maximum Safe Operating Area

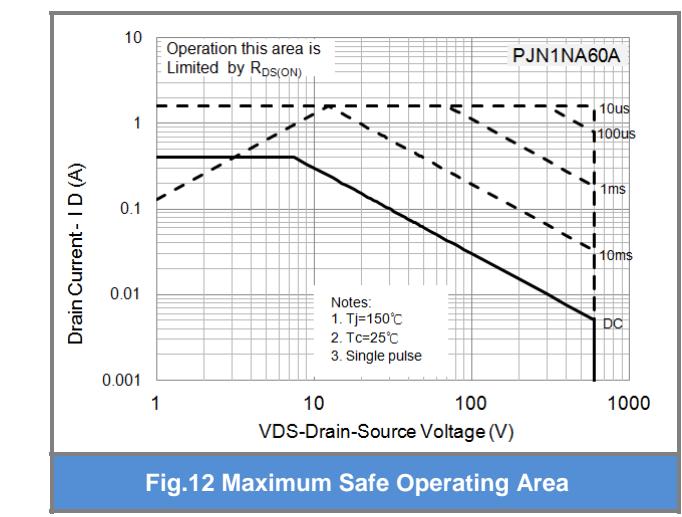


Fig.12 Maximum Safe Operating Area



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TYPICAL CHARACTERISTIC CURVES

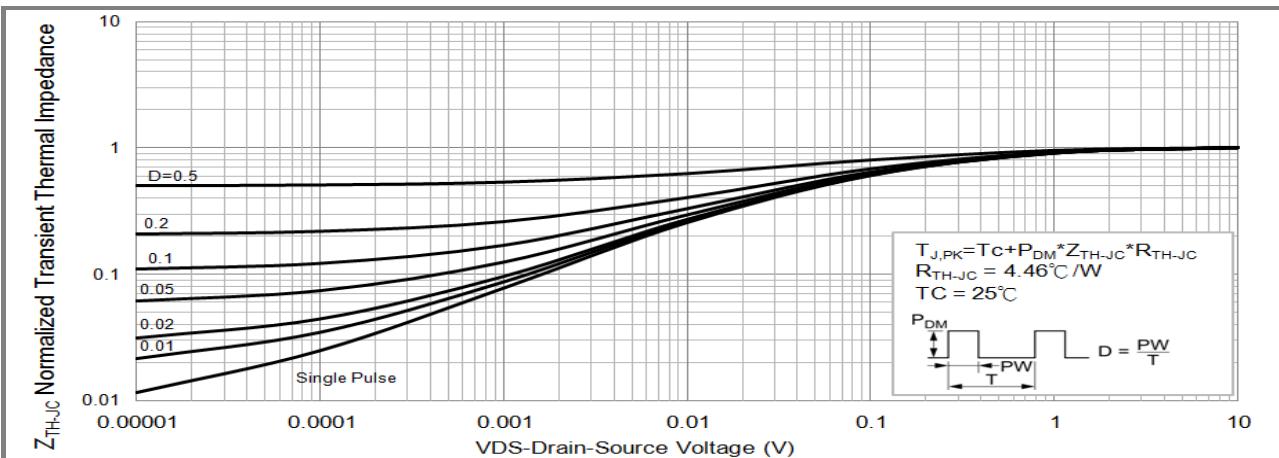


Fig.12 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

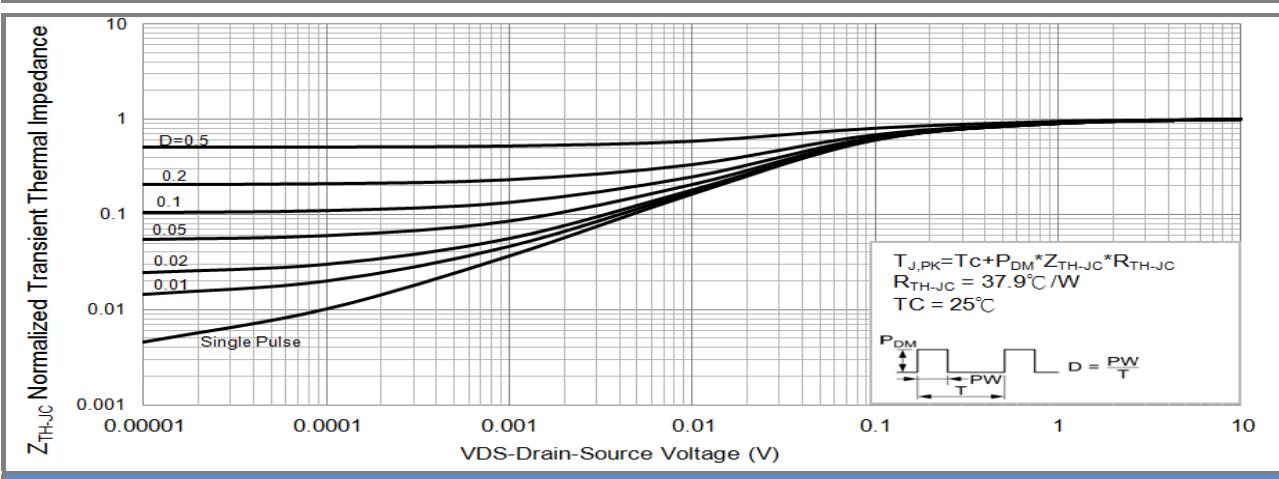


Fig.13 PJW1NA60A Normalized Transient Thermal Impedance vs. Pulse Width

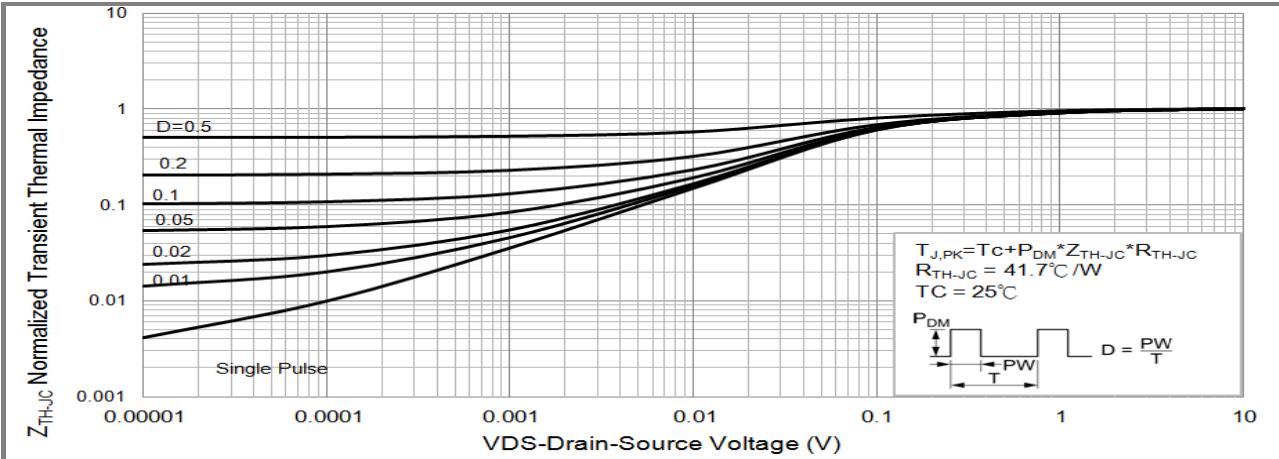
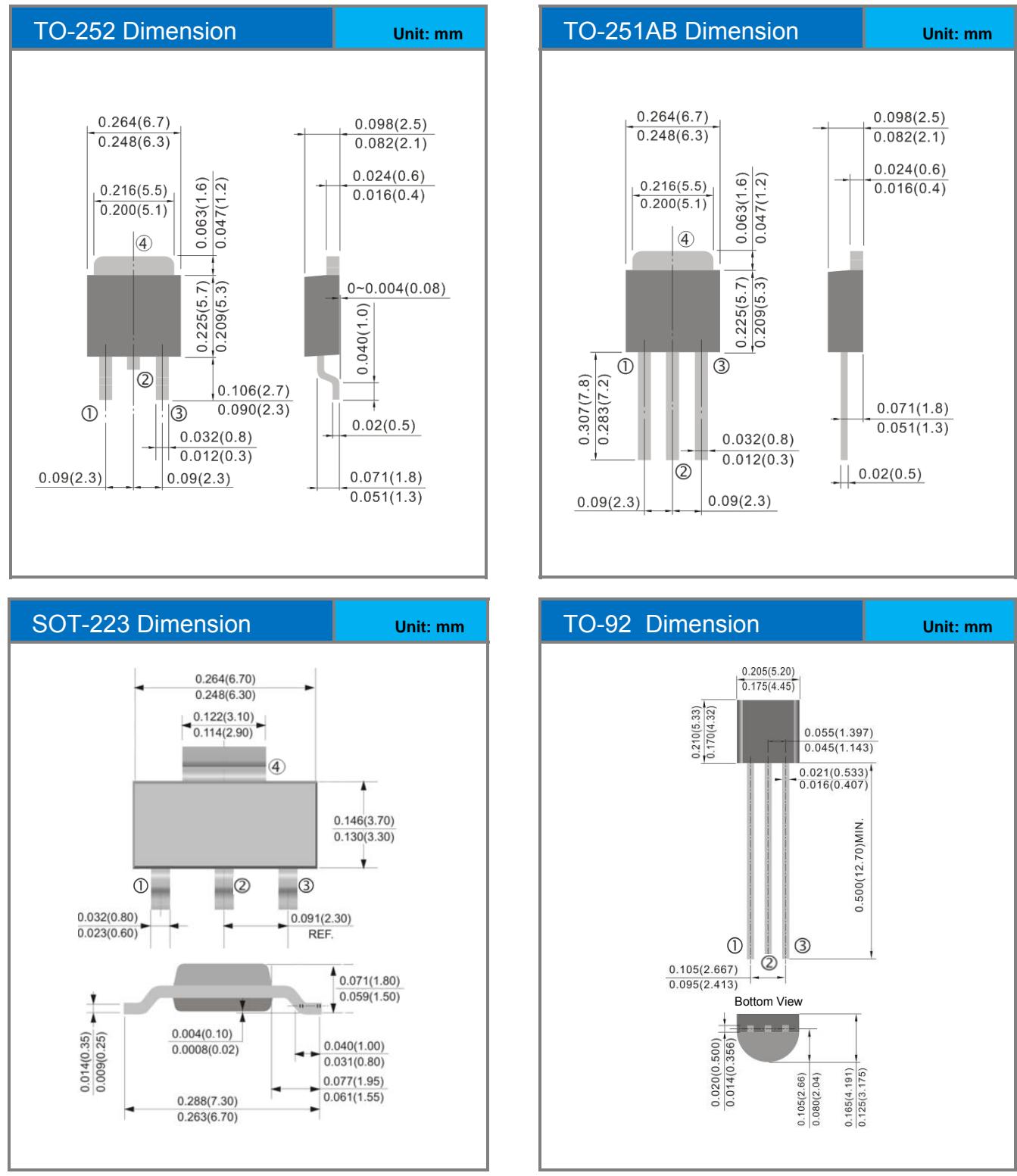


Fig.15 PJN1NA60 Normalized Transient Thermal Impedance vs. Pulse Width



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Packaging Information





PJN1NA60A / PJW1NA60A / PJu1NA60A / PJD1NA60A

PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type | Marking | Version |
|----------------------|--------------|---------------------|---------|--------------|
| PJu1NA60A_T0_00001 | TO-251AB | 80pcs / Tube | U1NA60A | Halogen free |
| PJD1NA60A_L2_00001 | TO-252 | 3,000pcs / 13" reel | D1NA60A | Halogen free |
| PJW1NA60A_R2_00001 | SOT-223 | 2,500pcs / 13" reel | 1NA60A | Halogen free |
| PJN1NA60A_B0_00001 | TO-92 | 1000pcs / bag | 1NA60A | Halogen free |
| PJN1NA60A_A0_00001 | TO-92 AMMO | 2000pcs / box | 1NA60A | Halogen free |



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